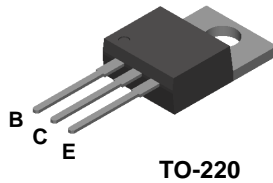
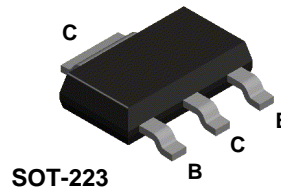


**D45C11**



**NZT45C11**



**PNP Current Driver Transistor**

This device is designed for power amplifier, regulator and switching circuits where speed is important. Sourced from Process 5P. See NZT751 for characteristics.

**Absolute Maximum Ratings\*** TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CEO</sub>	Collector-Emitter Voltage	80	V
I <sub>c</sub>	Collector Current - Continuous	4.0	A
T <sub>J</sub> , T <sub>stg</sub>	Operating and Storage Junction Temperature Range	-55 to +150	°C

\*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

**NOTES:**

- 1) These ratings are based on a maximum junction temperature of 150 degrees C.
- 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

**Thermal Characteristics** TA = 25°C unless otherwise noted

Symbol	Characteristic	Max		Units
		D45C11	*NZT45C11	
P <sub>D</sub>	Total Device Dissipation Derate above 25°C	60	1.2	W
		480	9.7	mW/°C
R <sub>θJC</sub>	Thermal Resistance, Junction to Case	2.1		°C/W
R <sub>θJA</sub>	Thermal Resistance, Junction to Ambient	62.5	103	°C/W

\*Device mounted on FR-4 PCB 36 mm X 18 mm X 1.5 mm; mounting pad for the collector lead min. 6 cm<sup>2</sup>.

**PNP Current Driver**  
(continued)

**D45C11 / NZT45C11**

**Electrical Characteristics**

TA = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Max	Units
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**OFF CHARACTERISTICS**

$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	$I_C = 100 \text{ mA}, I_B = 0$	60		V
$I_{CES}$	Collector-Cutoff Current	$V_{CB} = 90 \text{ V}, I_E = 0$		10	$\mu\text{A}$
$I_{EBO}$	Emitter-Cutoff Current	$V_{EB} = 5.0 \text{ V}, I_C = 0$		100	$\mu\text{A}$

**ON CHARACTERISTICS**

$h_{FE}$	DC Current Gain	$I_C = 0.2 \text{ A}, V_{CE} = 1.0 \text{ V}$ $I_C = 1.0 \text{ A}, V_{CE} = 1.0 \text{ V}$	40 20	120	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = 1.0 \text{ A}, I_B = 50 \text{ mA}$		0.5	V
$V_{BE(sat)}$	Base-Emitter On Voltage	$I_C = 1.0 \text{ A}, I_B = 100 \text{ mA}$		1.3	V

**SMALL SIGNAL CHARACTERISTICS**

$f_T$	Current Gain - Bandwidth Product	$I_C = 20 \text{ mA}, V_{CE} = 4.0 \text{ V}$	32		MHz
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FAST®	Quiet Series™	
FASTr™	SuperSOT™-3	
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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

## PRODUCT STATUS DEFINITIONS

### Definition of Terms

Datasheet Identification	Product Status	Definition
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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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